

L Number	Hits	Search Text	DB	Time stamp
1	200	(hiroyuki near2 nagasawa or takamitsu near2 kawahara or kuniaki near2 yagi).in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 11:29
2	54	((hiroyuki near2 nagasawa or takamitsu near2 kawahara or kuniaki near2 yagi).in.) and (sic or silicon adj carbide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 11:31
3	8	((hiroyuki near2 nagasawa or takamitsu near2 kawahara or kuniaki near2 yagi).in.) and (sic or silicon adj carbide) and attach\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 11:33
4	93	(sic or silicon adj carbide) and attach\$6 near5 coefficient	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 11:33
5	15	(sic or silicon adj carbide) same attach\$6 near5 coefficient	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 11:49
6	919	(sic or silicon adj carbide) and 117/84-109.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 11:49
7	130	(sic or silicon adj carbide) and 117/89.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 11:49
8	53	(sic or silicon adj carbide) and 117/89.ccls. and ((silicon or carbon) near2 source or (silane or propane))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 11:51
9	22	(sic or silicon adj carbide) and 117/89.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 11:52
10	10	117/89.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure) same (sic or silicon adj carbide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 13:14
11	60	117/84-109.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure) same (sic or silicon adj carbide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 13:15
12	0	117/84-109.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure) same (sic or silicon adj carbide) same alternat\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 13:16
13	1	117/84-109.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure) same (sic or silicon adj carbide) same cycl\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 13:16
14	6	117/84-109.ccls. and ((silicon or carbon) near2 source or (silane or propane)) same (rate or partial near2 pressure) same (sic or silicon adj carbide) same period\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/08 13:17

15	128	((sic or silicon adj carbide) and 117/84-109.ccls.) and source and cycle	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/08 14:50
16	10	sccm near10 (silicon or carbon) and (sic or silicon adj carbide) and 117/84-109.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/08 15:48
17	13	attach\$4 near3 coefficient and 117/84-109.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/08 15:48
18	73	puls\$4 same (deposit\$4 or growth) same (silicon adj carbide or sic) not laser	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/08 15:48